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Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

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Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







General purpose transistor (isolated transistor and diode)

QSL11

A 2SB1710 and a RB461F are housed independently in a TSMT5 package.

Applications

DC / DC converter Motor driver

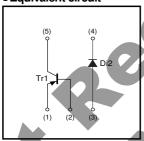
Features

- 1) Tr : Low VcE(sat) Di : Low VF
- 2) Small package

Structure

Silicon epitaxial planar transistor Schottky barrier diode

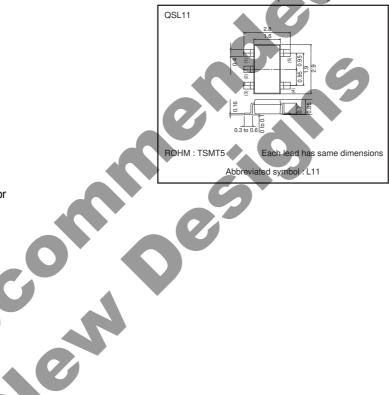
●Equivalent circuit



Packaging specifications

Туре	QSL11
Package	TSMT5
Marking	L11
Code	TR
Basic ordering unit(pieces)	3000

●External dimensions (Unit: mm)



● Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-base voltage	Vсво	-30	V
Collector-emitter voltage	VCEO	-30	V
Emitter-base voltage	VEBO	-6	V
Collector current	lc	-1	Α
	ICP	-2	A *1
Power dissipation	Pc	0.9	W/ ELEMENT*2
Junction temperature	Tj	150	°C
Range of storage temperature	Tstg	-40 to +125	°C

Di2

Parameter	Symbol	Limits	Unit
Peak reverse voltage	VRM	25	V
Reverse voltage (DC)	VR	20	V
Average rectified forward current	lF	700	mA
Forward current surge peak (60Hz, 1∞)	IFSM	3	A
Power dissipation	PD	0.7	W/ ELEMENT *
Junction temperature	Tj	125	°C
Range of storage temperature	Tstg	-40 to +125	°C

^{*} Mounted on a 25mm×25mm×10.8mm ceramic substrate

Tr1&Di2

Parameter	Symbol	Limits Unit
Total power dissipation	PD	0.5 W/ TOTAL *1
		1.25 W/ TOTAL *2

^{*1} Each terminal mounted on a recommended land *2 Mounted on a 25mm×25mm×10.8mm ceramic substrate

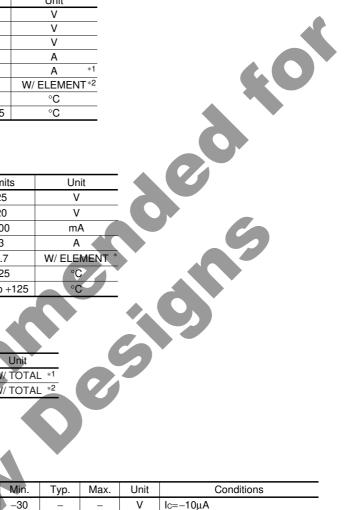
●Electrical characteristics (Ta=25°C)

Tr1

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	ВУсво	-30	_	_	V	Ic=-10μA
Collector-emitter breakdown voltage	BVceo	-30	_	_	V	Ic=-1mA
Emitter-base breakdown voltage	ВУево	-6	_	_	V	IE=-10μA
Collector cutoff current	Ісво	_	_	-100	nA	Vcb=-30V
Emitter cutoff current	ІЕВО	_	_	-100	nA	V _{EB} =-6V
Collector-emitter saturation voltage	V _{CE(sat)}	_	-150	-350	mV	Ic=-500mA, Iв=-25mA
DC current gain	hfe	270	_	680	_	Vce=-2V, Ic=-100mA*
Transition frequency	f⊤	_	320	_	MHz	Vc=-2V, Ie=100mA, f=100MHz *
Collector output capacitance	Cob	_	7	_	pF	Vcb=-10V, Ie=0A, f=1MHz
* Puland	·					<u> </u>

Di2

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	VF	_	450	490	mV	I _F =700mA
Reverse current	IR	_	_	200	μΑ	V _R =20V
Reverse recovery time	trr	-	9	-	ns	IF=IR=100mA, Irr=0.1IR



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^{*1} Single pulse, Pw=1ms *2 Mounted on a 25mm×25mm×10.8mm ceramic substrate

•Electrical characteristic curves

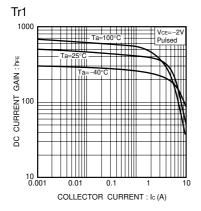


Fig.1 DC current gain vs. collector current

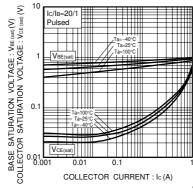


Fig.2 Collector-emitter saturation voltage base-emitter saturation voltage vs. collector current

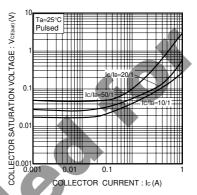


Fig.3 Collector-emitter saturation voltage vs. collector current

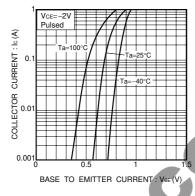


Fig.4 Grounded emitter propagation characteristics

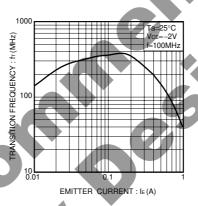


Fig.5 Gain bandwidth product vs. emitter current

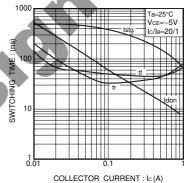


Fig.6 Switching time

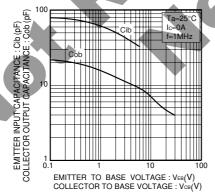
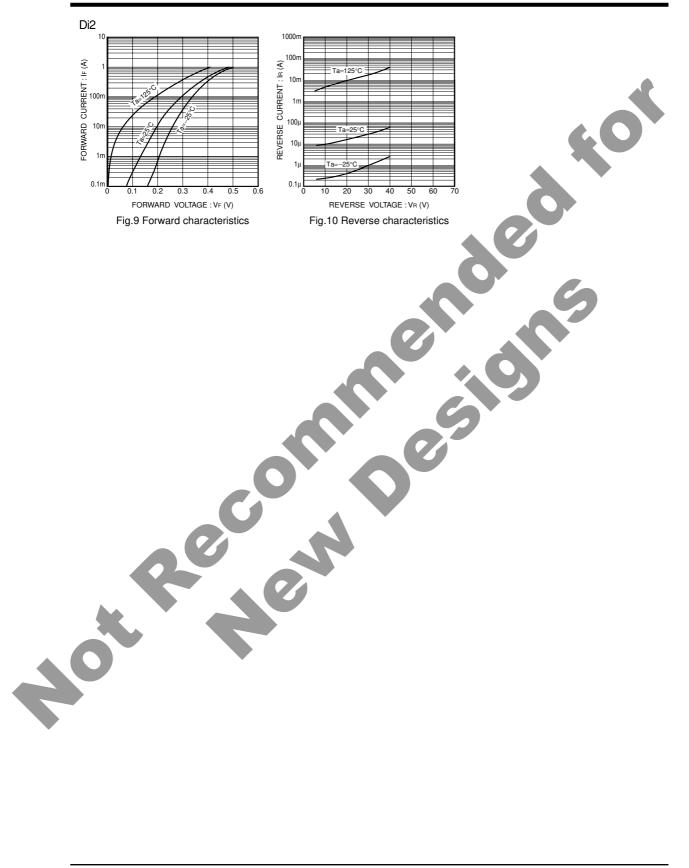


Fig.7 Collector output capacitance vs. collector-base voltage Emitter input capacitance vs. emitter-base voltage



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